The History of Silicon Detectors for Particle and X-ray Physics

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The Very Early Days of Solid State Detectors

Idea of solid state ionization chamber and first successful realisations:

- 1943: P.J. von Heerden, Utrecht (AgCl)
- 1949: K.G. McKay, Bell (Ge pn junction)
- 1955 1965: Si mono-crystals available
- → surface barrier detectors at several labs. Oak Ridge, Chalk River, CEA, ... main motivation nuclear particle spectrometers
- 1961: G. Dearnaley, Harwell : first segmented detector a pixel detector !
- 1970: first strip detectors Argonne, Fermilab, Karlsruhe, Southampton; for nuclear physics and nuclear medicine
- 1970: W.S. Boyle and G.E. Smith, Bell CCD

Several companies in the US and Europe for detector fabrication (> 7 in 1975)



typical values for Si:

- voltage: 50 500 V
- thickness: 0.05 1 mm
- signal: 1e/h-pair/3.6 eV
- -> mip 25000 charges/0.3 mm
- collection time: 5-50 ns
- · diffusion: few $\mu \textbf{m}$
- sensitive to light < ~1 μm, xrays 0.2-~20keV, charged part.



The Very Early Days

Si-detectors can also be used to detect minimum ionizing particles !



Fig. 4. Energy distribution produced in C56 by electrons of energy 150 MeV (momentum resolution $\approx 2\%$). The solid curve is given by Landau's theory.

Early Realization of Double Sided Strip Detector

S.M.Gruner BSC-thesis (1972):





- (.6×.6) mm²×50 µm n-type Si
- B-diffused (+Al): p⁺n-junction
- Au strips: np-junction
- test with ⁹⁰Sr source + amplifier + scope



Conclusion

The feasibility of initiating the fabrication of a large area integrated circuit sericonductor detector following our basic design has been demonstrated both conceptually and experimentally. The initial fabrication of a small test device has shown that the construction problems can be overcome. Further, testing of the small device has yielded attractive resolution in space and time (20 microns; 10 nano-seconds) and has done so with a signal to noise ratio which allows digital logic handling.



The Very Early Days of Si Detectors in hep

Segmented active target 1973 (G. Bellini et al. , NA-1 at CERN Coherent production $\pi + \text{Si} \rightarrow 3\pi + \text{Si}$; and later for charm)





Fig. 3. Silicon disk.

Fig. 5. Assembly of the whole telescope.

Surface barriers: a "mystic" art

- reliability not guaranteed
- but successful experiments and great potential
- → limited use

This changed in 1974 with

- discovery of J/ψ
- paper by Gaillard, Lee und Rosner on charmed particles
- discovery of charm (1975) (lifetime $c\tau \sim 100 \ \mu m$)
- discovery of $\tau\text{-lepton}$
- discovery of beauty
- → Hunt for high position resolution electronic detectors

(a friendly competition between gaseous and solid state approach)



The Hunt for High Resolution Electronic Detectors

But there are 3 reasons why the development of high position resolution Si-detectors took off in the late seventies:

- discovery of short-lived particles; lifetime $c\tau$ ~ 100 μm defines required resolution
- highly developed Si-technology for electronics (crystals + the planar process)
- development of miniaturized electronics (thick film hybrids
 → VLSI) generally available
- → Several hep groups started to learn the art of silicon sensors and µ-electronics (in close collaboration with industry)



high resolution bubble chambers: SLAC - CERN (production charm-anticharm)



The Early Days of Si Strip Detectors in hep

Still surface barrier technology: **PISA group** (Amendolia et al. 1980) \rightarrow Si-strip sensor with 600 μ m pitch



- CERN group (Hyams et al. 1980) Si-strip sensor with 300 μ m pitch
- demonstrate vertex reconstruction (within the NA-11 experiment)
- demonstrate capacitive charge division (thanks to broken channels)







Fig. 10. Hit distribution over 24 strips in the 10 GeV beam. Amplifiers on strips 43, 44, 52 and 62 were not working. Strip 59 has a broken contact, but its signals are collected on either 58 or 60. Robert Klanner - Univ. of Flumoury - INVOKID-10 T.- 1. July LUII

Transfer of the Planar Process to Detector Fabrication

Kemmer 1979, TU-München, transferred the highly developed Si-technology

for electronics to detector fabrication + industry (P. Burger - Enertec/Canberra)



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Getting Organized

1983: 3rd European Symposium on Semiconductor Detectors at Munich





Si-strip Detector Telescope in CERN NA11 Experiment

NA-11/32 experiment:

- spectrometer for the study of hadronic reactions eg π Be->charm+X
- 1981: 6 planes Si-strip detectors
 - * 24×36mm², 1200 strips/sensor
 - * strip pitch 20 $\mu\text{m},$ 280 μm thick
 - * 60 μ m readout $\rightarrow \sigma$ =5.4 μ m
 - * 120 μ m readout $\rightarrow \sigma$ =7.8 μ m
 - * total <2000 channels
 - * 100% efficiency

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Results from the NA11 Experiment

NA-11/32: Charm physics results

- lifetimes D^+ , D^0 , D_S , Λ_c , ...
- observation and mass of D_{S_2}
- hadronic production of charm particles (QCD)

Impact of NA11/32:

- demonstrated excellent performance of Si-strip detectors
- demonstrated excellent performance of pixel detectors
 (→ CCDs have been added in NA32)
- testing ground for new ideas and concepts (→ Si drift ch.)
- learning- + communicationenvironment for junior and senior Si-experts

(R.Horisberger, D.Dorfan, S.Parker, V.Lüth, + many more)







From MARK-II to LHC

Following the pioneering success of MarkII \rightarrow Si vertex detectors for all 4 LEP-detectors, TeVatron, B-factories, HERA, RHIC and \rightarrow LHC Example: CMS Tracker the largest Si tracker ever built! precision tracking in the harsh LHC environment for $|\eta| < 2.5$

Strip detectors:

- 9.3 M channels
- \cdot 210 m² sensor area
- 10 barrel layers
- 9 (+3) endcap disks

(Hybrid) Pixel detectors:

- 66 M channels
- \cdot ~1.1 m² sensor area
- 3 barrel layers
- 2 endcap disks
- innermost layer at r=4.3 cm



Tracker running with 97.8 % strips and 96.5 % pixels operating at design resolutions and efficiencies



CMS Tracker The building blocks of the Si-strip modules and Si-pixel modules



Quasi-industrial assembly (quality control!)





CMS Tracker - "The non-sleeping Beauty"

View of the CMS Tracker during installation in 2007



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CMS Tracker: Producing Physics Results





Silicon Detectors in hep and Space Experiments

Silicon detector area [m²] in different experiments: 1981 - now



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Si-Strip Detectors for X-ray Science



Figure 1

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(a) Photograph of the MYTHEN detector installed at the powder diffraction station at the SLS and (b) a zoom on the modules building the detector. The numbers indicate the main elements of interest: (1) MYTHEN detector layer; (2) He-filled box behind which is fixed the data acquisition system; (3) analyzer crystal detector; (4) center of the diffractometer; (5) beampipe; (6) silicon microstrip sensor; (7) front-end electronics; (8) connector to the data acquisition system.

B.Schmitt et al., NIM-A 501(2003)267

Just one example: MYTHEN (PSI)

Si-strip sensors: 320 µm thickness 1280 8 mm long strips with 50 µm pitch

- counting rate: > 2×10⁶ per strip
- max. no counts 24 bits (16,777,216)
- energy range 5keV (90%) 30 keV (8%)
- frame rate: 25Hz (24bit) 500Hz (4bit)



A highly successful example:

- reduction of measurement time for powder diffraction by ~10,000
- \rightarrow acquire data before radiation damage
- \rightarrow time resolved measurements possible

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Pixel Detectors: Invention and Principle of CCD

2009 Nobel prize: W.S.Boyle and G.E.Smith

Invention Charged Coupled Device, the first (practical) solid state imaging device

Test device 1 week after idea! (1970)

Picturephone
+ CCD inventors

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G.E.Smith NIM-A 607(2009)1

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Principle of charge shift



Shift pattern for 2-d CCD



CCDs as Pixel Detectors for Photon Science

Use of CCDs for imaging pioneered by astrophysics

- high sensitivity compared to film
- low noise (few electrons when cooled)

For X-rays: external scintillator \rightarrow record image



CCDs as Precision Position Detectors in hep



 \rightarrow superior pattern recognition convincingly demonstrated

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CCDs: VXD3 Vertex Detector for SLD@SLC

VXD3@SLD

- -installed in 1995
- -307 MPixels (ATLAS: 80Mpixels !)
- -0.4% X_0 (multiple scattering)
- -1st layer < 3cm from beam)

By far most performing vertex detector in terms of resolution → reference point for ILC vertex detectors





Hybrid Pixel Detectors

Idea: separate sensor and electronic \rightarrow flexibility but additional material Concept: Special features:



Pixel electronics (just one example)



Special features:

- read-out chip directly mounted on top of detector by bump bonding
- every pixel has its own electronics
- technology for electronics and sensor can be chosen separately (eg high-Z sensor + Si readout; optimize for radiation hardness,...)

Limitations:

- amount of material for precision vertex detector (multiple scattering!) also power dissipation – cooling
- read-out speed and dynamic range (in particular for X-ray science)

Hep experiments using hybrid pixels:

- CMS (66 Mpixels of 150×100 $\mu\text{m}^2\text{)}$
- ATLAS (80 Mpixels of 40×400 $\mu\text{m}^2\text{)}$
- ALICE, PHENIX (BNL), FAIR-expts. (PANDA, CBM, ...) ...



Early Hybrid Pixel Detector for X-rays

First Ge pixel detector in 1961 G. Dearnaley

S.Gaalema at 1984 IEEE-NSS







Performance:

- 600×600 pixels (20 μ m)²
- 50 e (rms) noise
- random access to every pixel
- average power 1 µW/pixel (for 1kHz readout)

was used to read out Si and Ge detectors

S.Gaalema IEEE Trans. NS-32, No.1(1985) 417



Charge Integrating Hybrid Pixel Detector for X-rays

Task: Fast time resolved imaging with μ s frame rate \rightarrow counting not an option \rightarrow integrating readout **Application:**

> us time-resolved x-ray radiography of multiphase, direct-injection gasoline fuel spray

\rightarrow Verify fluid dynamics simulations



Supersonic jet of Diesel fuel spray in 1 atm SF_6

- image area (61.7×7.5) mm² [built-up from images (13.5×2.5) mm²]
- shockwave: increase in gas density ~15%

MacPhee et al., Science 295(2002)1261



Specifications and performance:

- Si: 92×100 pixels, $(150 \ \mu m)^2$; 300 μm thick
- 8 storage cells; min. integration time 1 µs
- capacity: 17,000 8.9keV X-rays
- non-linearity <0.2% (full range)
- noise: ~20 keV (X-rays)
- 1.2µm HP process; GEC-Marconi bump bond
- 100 µW power/pixel
- limited radiation hardness
 - G.Rossi et al J.Synchr.Rad 6(1999)1096

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X-ray Counting Hybrid Pixel Detector(s)

Several examples: Medipix1, Medipix2, Medipix3, PILATUS1, PILATUS2, ADSC,... development chains \rightarrow continuous improvements + profit from technology advance

Example: PILATUS (PSI)- specifications and performance:

- pixelsize: (172 µm)²
- max. rate: 1.5 MHz/pixel
- dynamic range: 20 bits (1,048,576) no noise !
- read-out time: 5 ms
- frame rate: 10-100 Hz





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X-ray Counting Hybrid Pixel Detector(s)





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Pixel Detectors in hep

Hybrid-Pixels in use in hep since 1995 needs micro-electronics because of large no. of channels !

- pioneered in fixed target heavy ion expts. at CERN
- e⁺e⁻ colliders (DELPHI)
- pp- and ion-collider; in particular ATLAS, CMS, ALICE

CMS Pixel Detector: 66 Mio. pixels

- 3 barrel layers at 4.3, 7.2, 11.0 cm
- 2 forward disks





Performance from data: position resolution $\sigma_x = (12.8 \pm 0.9)\mu m$; $\sigma_y = (32.2 \pm 1.4)\mu m$

- \rightarrow design specifications achieved
- \rightarrow highly efficient b-tagging / secondary vertex recognition in complex environment
- \rightarrow essential tool to search for New Physics at the LHC



MAPS: Monolithic Active Pixels

For hep: inactive material + sensor thickness \rightarrow interactions + multiple scattering \rightarrow degradation of performance (in particular for e⁺e⁻) \rightarrow monolithic sensor - readout and thinning of substrate Example: CMOS-MAPS (R. Turchetta et al., NIM-A 458(2001)677)



- problem: readout time
- low power -

- random access



MAPS: Monolithic Active Pixels

State of the art: MIMOSA-26 (EUDET-telescope)

- 0.35 μm CMOS OPTO process
- 572×1152 pixels of (18.4 μ m)² \rightarrow 10mm×21mm
- 80 MHz read-out: zero supressed, binary with data sparsification → reduction of data volume by factor 10 1000 (depending on occupancy)
- 112 μs integration time



Drift Detectors: The Principle of Sideward Depletion



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Principle of Sideward Depletion



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Si Drift Detector as 2-D Tracking Detector

- Cathode strips \rightarrow drift field
- segmented anode \rightarrow transverse position time-of-flight \rightarrow longitudinal pos.



achieved performance: 2 μm in lab (laser light) 10 μm in test beam 18 μm in actual experiment



Emilio Gatti and Pavel Rehak: Silicon Drift Detector SDD







The Family of Detectors Based on Sideward Depletion





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- charge from entire thickness collected and stored in potential trough (below Φ_2)
- by modulating potentials $\Phi_i \rightarrow$ transfer charges until they reach read-out electrode(s)
- channel stops prevent that charges spill to neighbouring rows (eg from $n \rightarrow n\pm 1$)
- \rightarrow high quantum efficiency for X-rays due to full depletion (CMOS CCDs ~ 20 μ m thick !)
- \rightarrow backside illumination allows for thin entrance window (min. detectable X-ray energy !)
- \rightarrow high transfer efficiency (uniform response)
- \rightarrow pixel size down to ~30 μm

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 \rightarrow good radiation hardness because of pn junctions (no potential steering through oxide)

pn CCDs in Heaven

XMM-Newton satellite





elemental analysis of TYCHO supernova remnant:

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Detectors at the LCLS and other FELs

Experiments at FELs \rightarrow unprecedented requirements for detectors:

- energy resolution and dynamic range (0 \rightarrow 10⁵ photons)
- segmentation and readout-speed
- charge densities and radiation dose (1 GGy @ EXFEL)
- Beautiful instruments existing + under developments \rightarrow iWoRID13

Example for a running detector: CAMP (CFEL MultiPurpose) detector

Femtosecond X-ray Protein Nanocrystallography

Example: CAMP@LCLS

- Most macromolecules cannot be grown to crystals of sufficent size for conventional crystallography^{*})
- X-ray dose required to study crystals will destroy them
- can fs pulses at FELs produce diffraction pattern before damage occurred?
- experiment with CAMP at LCLS: 10¹² 1.8keV γ/pulse of 10, 70 and 200 ns, focussed to 7µm (FWHM) → 70 MJ !
- record 3M diffraction patterns of 0.2-2µm nanocrystals of photosystem I (structure known)
- *) so far only 300 unique structures of membrane proteins deciphered !

Figure 1 | Femtosecond nanocrystallography. Nanocrystals flow in their buffer solution in a gas-focused, 4- μ m-diameter jet at a velocity of 10 m s⁻¹ perpendicular to the pulsed X-ray FEL beam that is focused on the jet. Inset, environmental scanning electron micrograph of the nozzle, flowing jet and focusing gas³⁰. Two pairs of high-frame-rate pnCCD detectors¹² record low-and high-angle diffraction from single X-ray FEL pulses, at the FEL repetition rate of 30 Hz. Crystals arrive at random times and orientations in the beam, and the probability of hitting one is proportional to the crystal concentration.

H.Chapman et al., Nature 470(2011)73

Femtosecond X-ray Protein Nanocrystallography

Diffraction pattern of single 70 fs pulse

Structure (c) 70 fs pulse; (d) conventional method truncated to 8.5 Å resolution

Single shot femtosecond nanocrystallography demonstrated !

- ightarrow excellent Si detectors were necessary for this success
- → further developments are required and under way to meet the challenges of the new X-ray sources - one of the main themes of IWORID13

Outlook and Summary

Looking back on > $\frac{1}{2}$ a century of development of solid state sensor and detector systems:

- an exciting story of fascinating developments
- solid state detectors enabled important discoveries + precision measurements
- the developments have major impact on industry and science outside of physics
- frequently there has been amazingly little exchange between groups
- the close collaboration between academia and industry has been importan

Looking forward:

- rapidly developing technologies bring new opportunities they will help solving the many challenges posed by the new science ideas and the new experimental facilities, like Free-Electron Lasers, the High-Luminosity LHC, the International Linear Collider, etc.
- I also hope that there will also be completely new ideas, like in the past the CCD, the concept of sideway depletion, the DepFET and more

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